HIGH-VOLTAGE MONOLITHIC IC

ECN3061

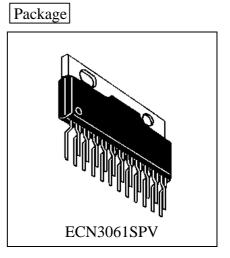
ECN3061 is a one-chip three-phase bridge inverter IC which has 6 IGBTs in the circuit. Especially, it is very suitable for controlling the speed of three-phase DC brushless motors which are applied to AC100~110V power supplies.

Functions

- A Charge pump circuit is integrated.
- Free wheeling diodes are integrated.

Features

- It can be controlled by PWM with 6 inputs from an external microprocessor.
- 6 logic inputs are compatible with 5V CMOS and LSTTL outputs.
- 6 IGBTs can be operated in 20kHz chopping frequency.



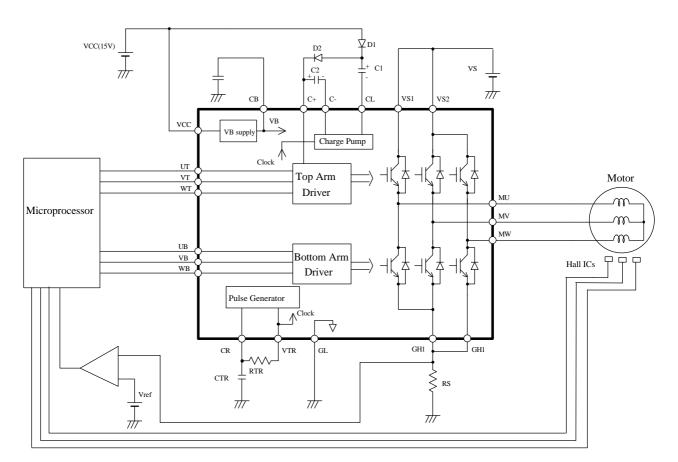


Fig.1 Block Diagram

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PDE-3061-0

- 1. General
 - (1) Type

i)ECN3061SP ii)ECN3061SPV iii)ECN3061SPR

- (2) Application 3-phase DC brushless motor
- (3) Structure Monolithic IC
- (4) Package SP-23T

2. Maximum Allowable Ratings (Ta=25°C)

No.	Items	Symbols	Terminal	Ratings	Unit	Condition
1	Output Device	VSM	VS1,VS2	250	V	
	Breakdown Voltage		MU,MV,MW			
2	Supply Voltage	VCC	VCC	18	V	
3	Input Voltage	VIN	UT,VT,WT,	-0.5 ~ VB+0.5	V	
			UB,VB,WB			
4	Output Current	IMDC	MU,MV,MW	1.0	Α	
5	Peak Output Current	IMP	MU,MV,MW	1.8	Α	Note 1
6	Output Current in Start	IOM	MU,MV,MW	1.8	Α	Note 1
	Up and Accelerating					
7	Operating Junction	Tjop		-20 ~ +125	°C	Note 2
	Temperature					
8	Storage Temperature	Tstg		-40 ~ +150	°C	

Note1. Please note that the duty for a period exceeding 1A has to be less than 5% of total current flowing period. Note2. Thermal resistance

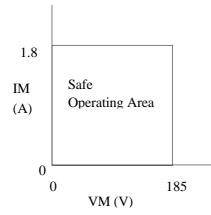
 $\begin{array}{rcl} \text{Rj-c} &= 4 \quad ^{\circ}\text{C/W} \\ \text{Rj-a} &= 40^{\circ}\text{C/W} \end{array}$

3. Recommended Operating Conditions

No.	Items	Symbols	Terminal	MIN	TYP	MAX	Unit	Condition
1	Supply Voltage	VS	VS1,2	90	141	185	V	
2		VCC	VCC	13.5	15	16.5	V	

Note 1. Recommended Safe Operating Area(SOA)

This IC should be used within the SOA as shown below, where IM and VM are the current and the voltage at the terminals connected to motor coils when the phase is changed (turned off).



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Electorical Characteristics (Ta=25°C)
Unless otherwise specified, VCC=15V, VS=141V,
Suffix T: Top arm B: Bottom arm

N.	Suffix 1; 10p arm	,	Transie 1	MIN	TVD	MAX	TT!	O = 1111 = 1
No.	Items	Symbols	Terminal	MIN	TYP	MAX	Unit	Condition
1	Standby Current	IS	VS1,2	-	4.0	10	mA	UT,VT,WT,UB,VB,
2		ICC	VCC	-	10	20	mA	WB=0
3	Output device FVD	VFT	MU,MV,MW	I	2.0	3	V	I=0.7A
4		VFB	MU,MV,MW	-	2.0	3	V	
5	Turn On	TdONT	MU,MV,MW	I	0.5	3.0	μs	
6	Delay Time	TdONB	MU,MV,MW	-	0.5	3.0	μs	I=0.7A
7	Turn Off	TdOFFT	MU,MV,MW	-	1.0	3.0	μs	Resistance load
8	Delay Time	TdOFFB	MU,MV,MW	-	0.8	3.0	μs	
9	Diode FVD	VFDT	MU,MV,MW	-	2.0	2.5	V	I=0.7A
10		VFDB	MU,MV,MW	-	2.2	2.7	V	
11	Input Voltage	VIH	UT,VT,WT,	3.5	-	-	V	
12		VIL	UB,VB,WB	-	-	1.5	V	
13	Input Current	IIL	UT,VT,WT,	-	-	100	μΑ	Input=5V Note 1
			UB,VB,WB					Pull down Resistance
14	VB supply voltage	VB	CB	6.8	7.5	8.2	V	
15	VB supply current	IB	CB	25	-	-	mA	$\delta V_{LOAD} = 0.1 V$

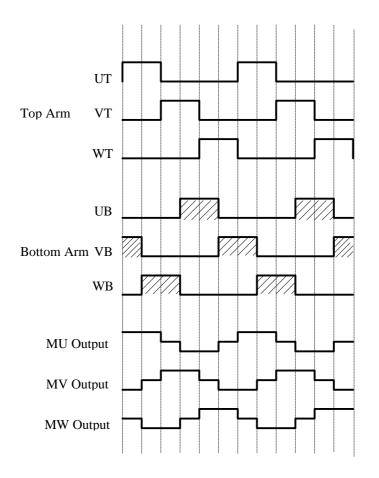
Note 1. A pull down resistance is typically 200 k $\Omega.$

5. Function

5.1 Truth Table

Terminal	Input	Output
UT,VT,WT,	L	OFF
UB,VB,WB	Н	ON

5.2 Timing Chart



6. Standard Application

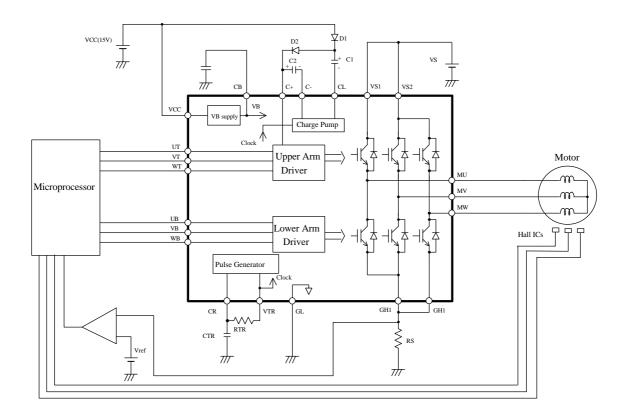
No.	Component	Recommended Value	Usage	Remark
1	C0	More than 0.22µF	for smoothing VB	The stress voltage is
			(VB; internal power supply)	8V.
2	C1,C2	$1.0\mu F \pm 20\%$	for a charge pump	The stress voltage is
				VCC.
3	D1,D2	Hitachi DFG1C4(glass mold)	for a charge pump	400V/1A
		Hitachi DFM1F4(resin mold)		t _{rr} ≤100ns
		or considerable parts		
4	CTR	1800 pF ± 5%	for an internal clock	Note 1.
5	RTR	$22 \text{ k}\Omega \pm 5\%$	for an internal clock	Note 1.

Note 1. The internal clock frequency is approximately determined by next equation.

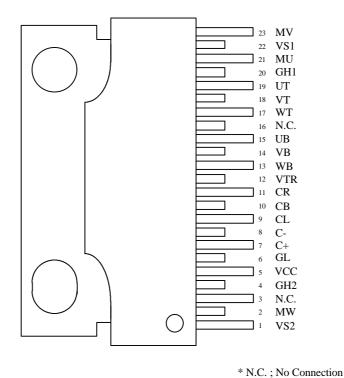
At recommended value of CR, the error factor of IC is about 10%.

 $f_{clock} = -1 \ / \ (2C*R*Ln(1-3.5/5.5)) \qquad ; \ Ln \ is \ natural \ logarithm.$

$$= 0.494 / (C*R)$$
 (Hz)



7. Terminal

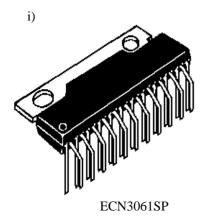


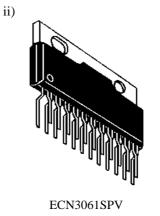
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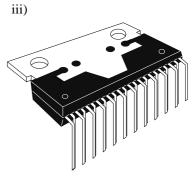




8. Package appearance



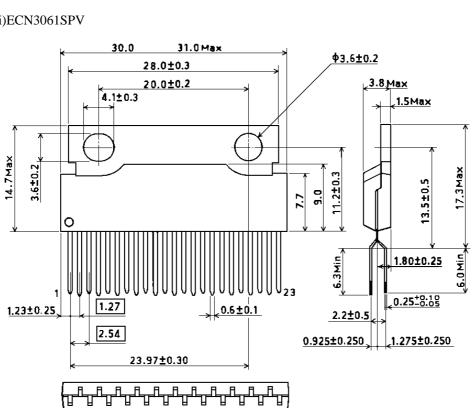




ECN3061SPR

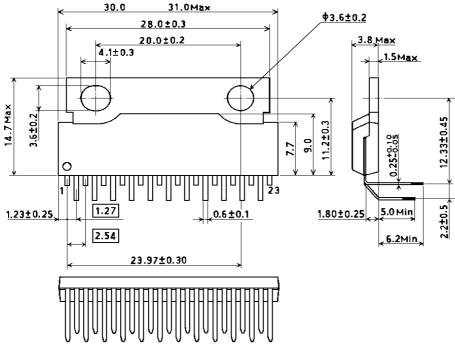
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ii)ECN3061SPV

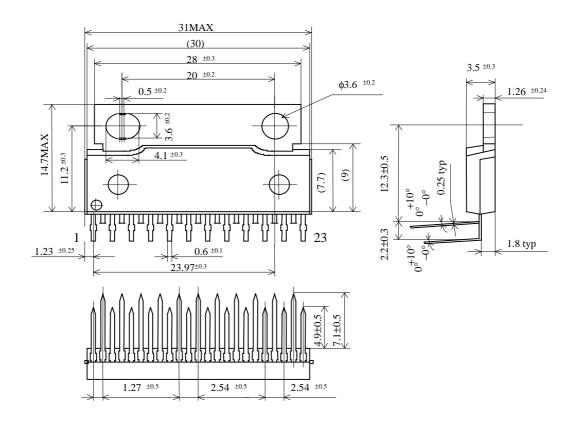
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9. Package dimensions i)ECN3061SP

ECN3061

30.0



HITACHI POWER SEMICONDUCTORS

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